SIEMENS

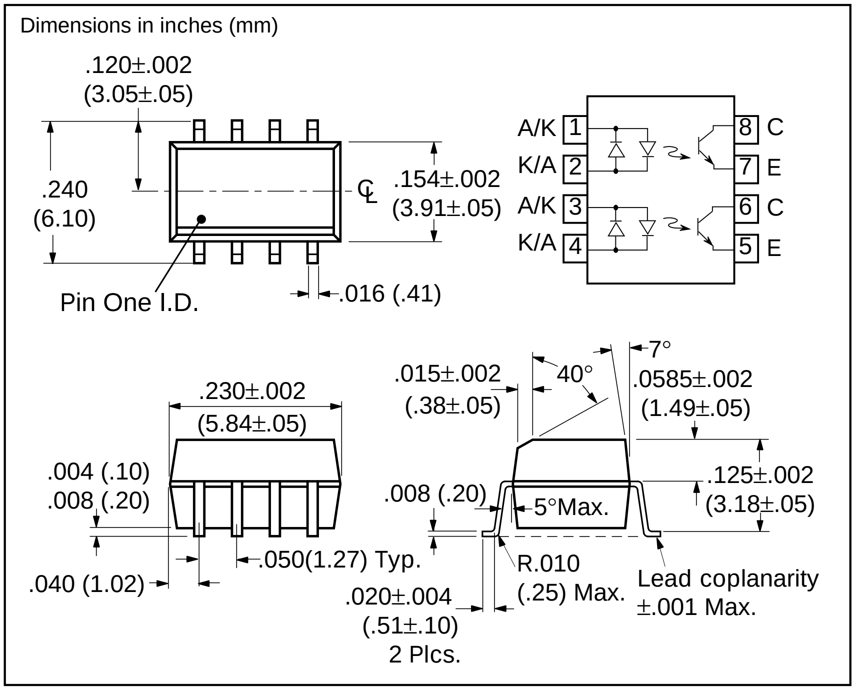
NEW

ILD256

DUAL AC INPUT PHOTOTRANSISTOR SMALL OUTLINE SURFACE MOUNT OPTOCOUPLER

FEATURES

- **Each Channel: Guaranteed CTR Symmetry, 2:1 Maximum**
- **Bidirectional AC Input**
- **Industry Standard SOIC-8 Surface Mountable Package**
- **Standard Lead Spacing, .05"**
- **Available in Tape and Reel Option (Conforms to EIA Standard 481-2)**



DESCRIPTION

The ILD256 is a dual channel optocoupler. Each channel consists of two infrared emitters connected in anti-parallel and coupled to a silicon NPN phototransistor detector.

These circuit elements are constructed with a standard SOIC-8 footprint.

The product is well suited for telecom applications such as ring detection or off/on hook status, given its bidirectional LED input and guaranteed current transfer ratio (CTR) of 20% at I_F= 10 mA.

Maximum Ratings

Emitter (Each Channel)

Continuous Forward Current ....30 mA
Power Dissipation at 25°C............................45 mW
Derate Linearly from 25°C......................0.5 mW/°C

Detector (Each Channel)

Collector-Emitter Breakdown Voltage...............70 V
Emitter-Collector Breakdown Voltage.................7 V
Power Dissipation ....55 mW
Derate Linearly from 25°C....................0.55 mW/°C

Package

Total Package Dissipation at 25°C Ambient
(LED + Detector) ....200 mW
Derate Linearly from 25°C......................2.0 mW/°C
Storage Temperature................... –55°C to +150°C
Operating Temperature ....–55°C to +100°C
Soldering Time at 260°C .... 10 sec.

Characteristics (T_A=25°C)

	Sym	Min.	Typ.	Max.	Unit	Condition
Emitter (Each Channel)						
Forward Voltage	V_F		1.2	1.55	V	I_F=±10 mA
Reverse Current	I_R		0.1	100	mA	V_R=6.0 V
Detector (Each Channel)						
Breakdown Voltage Collector-Emitter Emitter-Collector	 BV_{CEO} BV_{ECO}	 70 7			 V V	 I_C=10 µA I_E=10 µA
Leakage Current, Collector-Emitter	I_{CEO}		5	50	nA	V_{CE}=10 V
Package						
DC Current Transfer	CTR	20			%	I_F=±10 mA, V_{CE}=5 V
Symmetry $\frac{\text{CTR at + 10 mA}}{\text{CTR at -10 mA}}$		0.5	1.0	2.0		
Saturation Voltage, Collector-Emitter	V_{CEsat}			0.4		I_F=±16 mA, I_C=2 mA
Isolation Voltage, Input to Output	V_{IO}	2500			VAC_{RMS}	t=1 min.

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Figure 1. LED forward current versus forward voltage

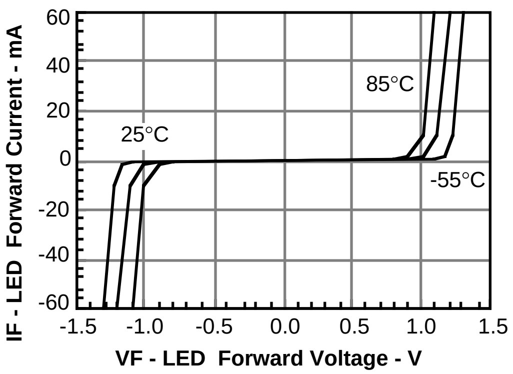

Figure 2. Forward voltage versus forward current

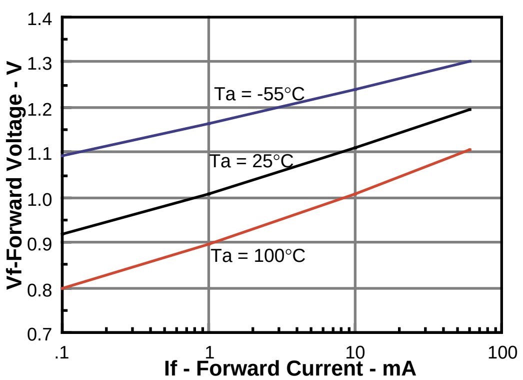

Figure 3. Peak LED current versus duty factor, Tau

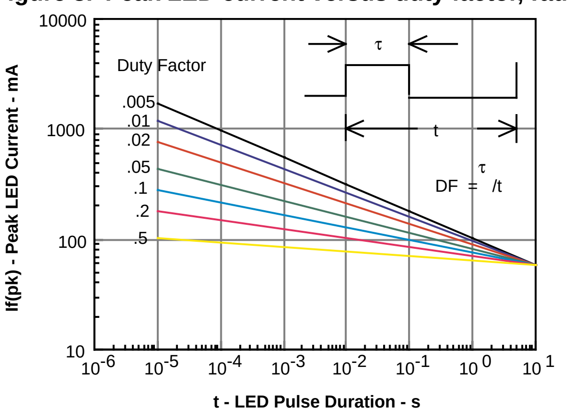

Figure 4. Normalized CTR versus If and Ta

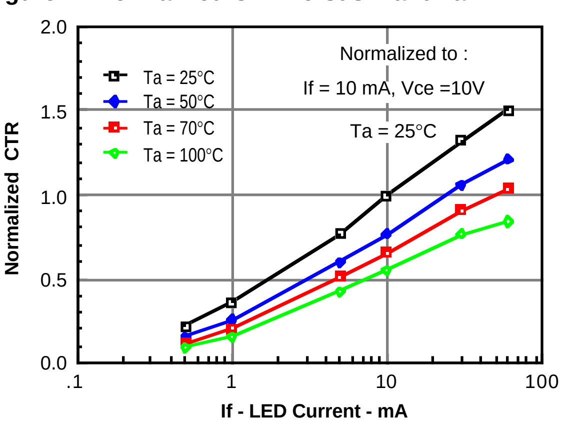

Figure 5. Normalized saturated CTR

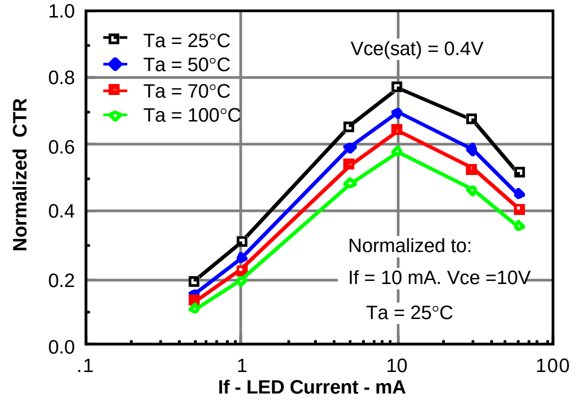

Figure 6. Normalized CTRcb

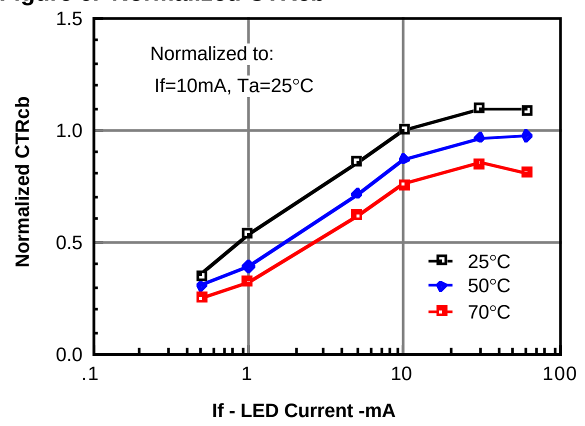

Figure 7. Photocurrent versus LED current

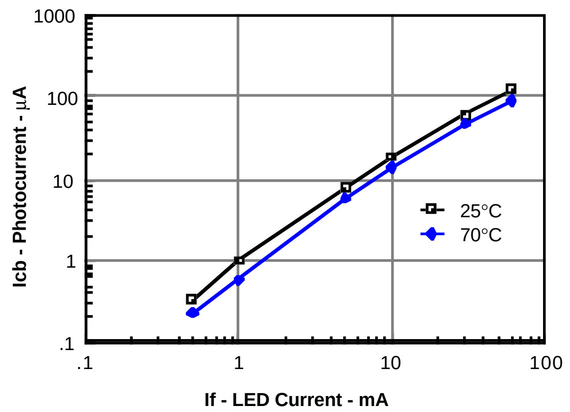

Figure 8. Base current versus If and HFE

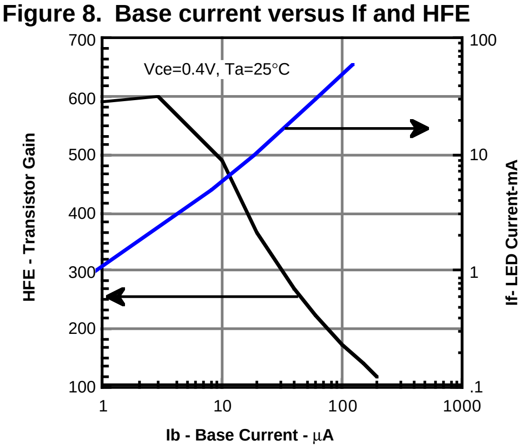

Figure 9. Normalized HFE versus Ib, Ta

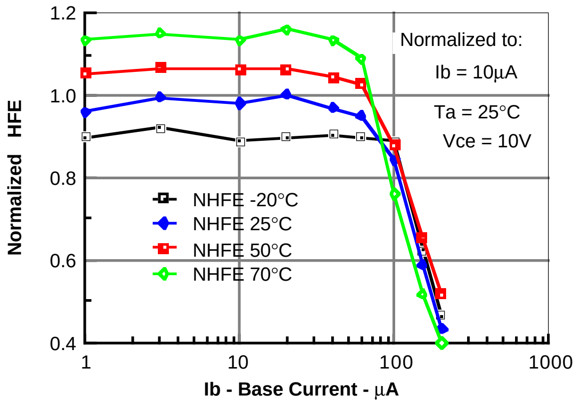

Figure 11. Base emitter voltage versus base

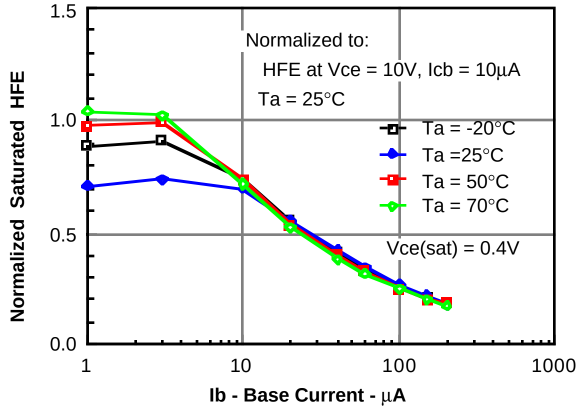

Figure 10. Normalized saturated HFE versus Ib

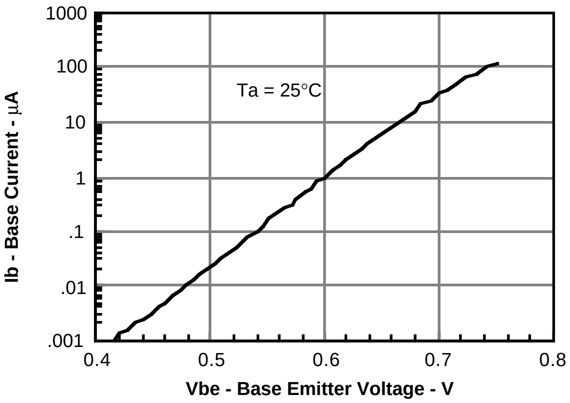

Figure 12. Collector-emitter leakage current versus temperature